

Description

The NTD4809N uses advanced trench technology

to provide excellent $R_{DS(ON)}$, low gate charge and

operation with gate voltages as low as 4.5V. This

device is suitable for use as a

Battery protection or in other Switching application.

D S G

TO-252-2L

General Features

 $V_{DS} = 30V I_{D} = 60 A$

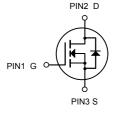
 $R_{DS(ON)} < 9m\Omega @ V_{GS}=10V$

Application

Battery protection

Load switch

Uninterruptible power supply



N-Channel MOSFET

Package Marking and Ordering Information

Product ID	Pack	Brand	Qty(PCS)
NTD4809N	TO-252-2L	HXY MOSFET	2500

Absolute Maximum Ratings (TC=25°C unless otherwise specified)

Symbol	Parameter	Parameter Rating	
Vos	Drain-Source Voltage	30	V
Vgs	Gate-Source Voltage	±20	V
I _D @T _C =25°C	Continuous Drain Current, V _{GS} @ 10V ¹	60	А
I _D @T _C =100°C	Continuous Drain Current, V _{GS} @ 10V ¹	40	А
I _D @T _A =25°C	Continuous Drain Current, V _{GS} @ 10V ¹	13.6	А
ID@T _A =70°C	Continuous Drain Current, V _{GS} @ 10V ¹	11.4	А
Іом	Pulsed Drain Current ² 110		А
EAS	Single Pulse Avalanche Energy ³ 57.8		mJ
las	Avalanche Current	34	А
P _D @T _C =25°C	Total Power Dissipation ⁴	41	W
P _D @T _A =25°C	Total Power Dissipation ⁴	Total Power Dissipation ⁴ 2.42	
Тѕтв	Storage Temperature Range	Storage Temperature Range -55 to 175	
TJ	Operating Junction Temperature Range	Operating Junction Temperature Range -55 to 175	
Reja	Thermal Resistance Junction-ambient (Steady State) ¹	ambient (Steady State) ¹ 62	
R _θ JC	Thermal Resistance Junction-Case ¹ 3.6		°C/W



Electrical Characteristics (T_J=25 °C, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BVDSS	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =250uA	30			V
△BVdss/△TJ	BVDSS Temperature Coefficient	Reference to 25°C , I _D =1mA		0.027		V/°C
		V _{GS} =10V , I _D =30A		7	9	
RDS(ON)	Static Drain-Source On-Resistance ²	V _{GS} =4.5V , I _D =15A		11	14	mΩ
V _{GS(th)}	Gate Threshold Voltage	V -V 1 -250A	1.2	1.5	2.5	V
$\triangle V_{GS(th)}$	V _{GS(th)} Temperature Coefficient	$V_{GS}=V_{DS}$, $I_D=250uA$		-5.8		mV/°C
IDSS	Drain-Source Leakage Current	V_{DS} =24V , V_{GS} =0V , T_J =25 $^{\circ}$ C			1	
IDSS	Diam-Source Leakage Current	V_{DS} =24V , V_{GS} =0V , T_J =55 $^{\circ}$ C		5 uA		uA
Igss	Gate-Source Leakage Current	V_{GS} = $\pm 20V$, V_{DS} = $0V$			±100	nA
gfs	Forward Transconductance	V _{DS} =5V , I _D =30A		38		S
Rg	Gate Resistance	V _{DS} =0V , V _{GS} =0V , f=1MHz		2.2	3.5	
Qg	Total Gate Charge (4.5V)			12.6	17.6	
Qgs	Gate-Source Charge	V _{DS} =15V , V _{GS} =4.5V , I _D =15A		4.2	5.9	nC
Q _{gd}	Gate-Drain Charge			5.1	7.1	
T _{d(on)}	Turn-On Delay Time			4.6	9.2	
Tr	Rise Time	V _{DD} =15V , V _{GS} =10V , R _G =3.3		12.2	22	
T _{d(off)}	Turn-Off Delay Time	I _D =15A		26.6	53	ns
Tf	Fall Time			8	16	
Ciss	Input Capacitance			1317	1843	
Coss	Output Capacitance	V _{DS} =15V , V _{GS} =0V , f=1MHz		163	228	pF
Crss	Reverse Transfer Capacitance			131	183	
Is	Continuous Source Current ^{1,5}				55	Α
Ism	Pulsed Source Current ^{2,5}	$V_G=V_D=0V$, Force Current			110	Α
VsD	Diode Forward Voltage ²	V _{GS} =0V , I _S =1A , T _J =25°C			1.2	V
t _{rr}	Reverse Recovery Time	IF=30A , dI/dt=100A/μs ,		9.2		nS
Qrr	Reverse Recovery Charge			2		nC

Note:

- 1 .The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper.
- 2.The data tested by pulsed , pulse width \leq 300us , duty cycle \leq 2%
- 3. The EAS data shows Max. rating . The test condition is V_{DD} =25V, V_{GS} =10V,L=0.1mH, I_{AS} =34A
- 4.The power dissipation is limited by 175°C junction temperature
- 5.The data is theoretically the same as I_D and I_{DM} , in real applications, should be limited by total power dissipation.



Typical Characteristics

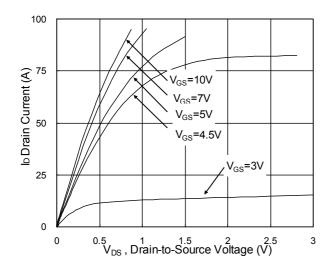


Fig.1 Typical Output Characteristics

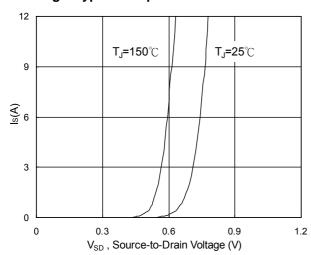


Fig.3 Forward Characteristics of Reverse

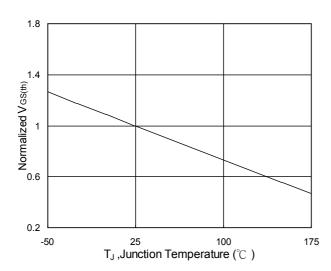


Fig.5 Normalized V_{GS(th)} vs. T_J

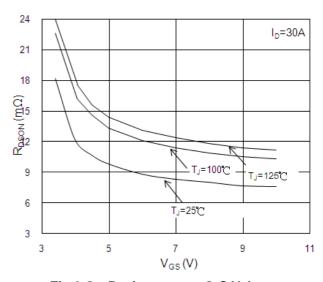


Fig.2 On-Resistance vs. G-S Voltage

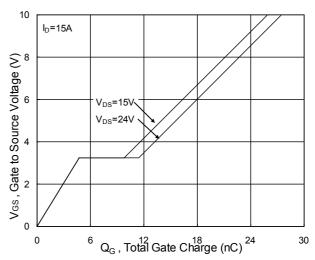


Fig.4 Gate-Charge Characteristics

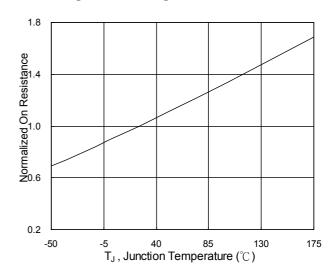
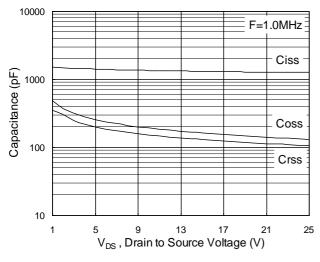


Fig.6 Normalized R_{DSON} vs. T_J



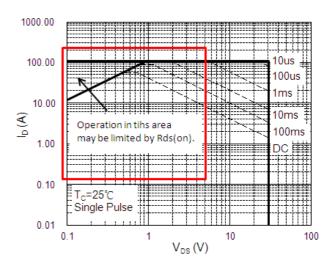


Fig.7 Capacitance

Fig.8 Safe Operating Area

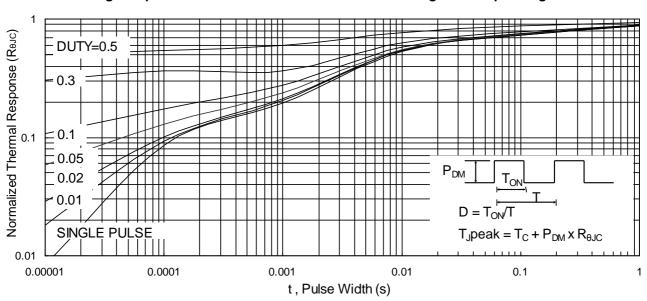
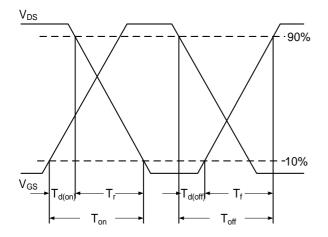
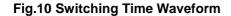


Fig.9 Normalized Maximum Transient Thermal Impedance





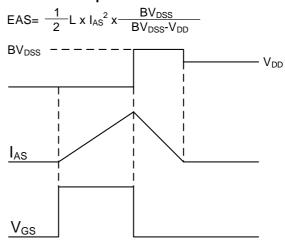
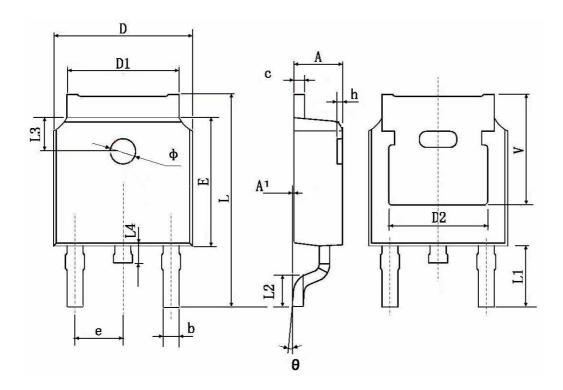


Fig.11 Unclamped Inductive Switching Waveform



TO-252-2L Package Information



Oh al	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
С	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	0.483 TYP.		0.190 TYP.		
Е	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900 TYP.		0.114 TYP.		
L2	1.400	1.700	0.055	0.067	
L3	1.600 TYP.		0.063 TYP.		
L4	0.600	1.000	0.024	0.039	
Ф	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.350	TYP.	P. 0.211 TYP.		

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